

# **Dual Wide Bandwidth Operational Amplifiers**

The MC4558AC, C combine all the outstanding features of the MC1458 and, in addition offer three times the unity gain bandwidth of the industry standard.

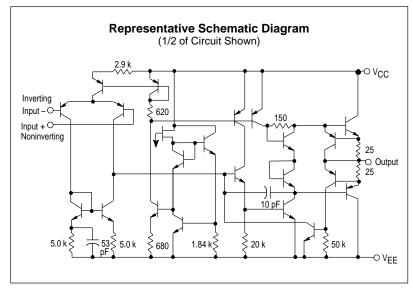
- 2.5 MHz Unity Gain Bandwidth Guaranteed (MC4558AC)
- 2.0 MHz Unity Gain Bandwidth Guaranteed (MC4558C)
- Internally Compensated
- Short Circuit Protection
- Gain and Phase Match between Amplifiers
- Low Power Consumption

Rating	Symbol	MC4558AC MC4558		Unit
Power Supply Voltage	V <sub>CC</sub> V <sub>EE</sub>	+22 –22	+18 –18	Vdc
Input Differential Voltage	VID	±3	V	
Input Common Mode Voltage (Note 1)	VICM	±1:	V	
Output Short Circuit Duration (Note 2)	tSC	Contin		
Ambient Temperature Range	ТА	0 to -	°C	
Storage Temperature Range	T <sub>stg</sub>	–55 to	°C	
Junction Temperature	Тј	15	°C	

#### **MAXIMUM RATINGS** ( $T_A = +25^{\circ}C$ , unless otherwise noted.)

**NOTES:** 1. For supply voltages less than ±15 V, the absolute maximum input voltage is equal to the supply voltage.

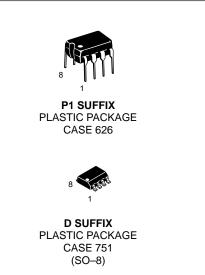
2. Short circuit may be to ground or either supply.

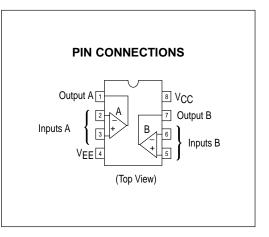


# MC4558AC MC4558C

## DUAL WIDE BANDWIDTH OPERATIONAL AMPLIFIERS

SEMICONDUCTOR TECHNICAL DATA





#### **ORDERING INFORMATION**

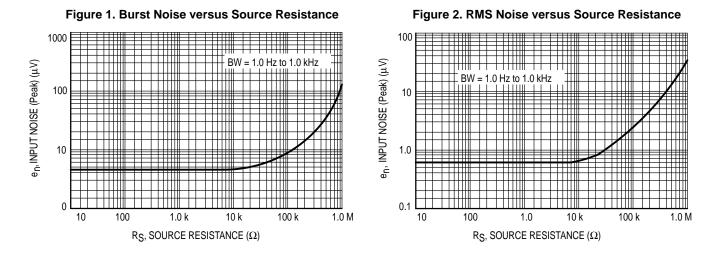
Device	Operating Temperature Range	Package
MC4558CD	$T_A = 0^\circ$ to +70°C	SO–8
MC4558ACP1,CP1	1A = 0 10 +70 C	Plastic DIP

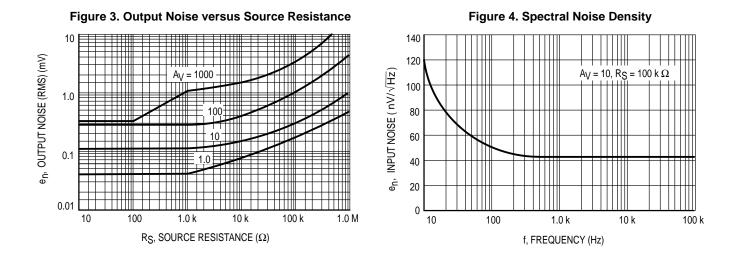
© Motorola, Inc. 1996

InducatoristicInducatoristicInducatoristicUnity Gain BandwidthCanaResR	<b>FREQUENCY CHARACTERISTICS</b> ( $V_{CC} = +15 V$ , $V_{EE} = -15 V$ , $T_A = 25^{\circ}C$ )								
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Characteristic	Symbol	MC4558AC			MC4558C			Unit
$      Input Offset Voltage (Rg \le 10 kΩ)                                   $			Min	Тур	Max	Min	Тур	Max	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Unity Gain Bandwidth	BW	2.5	2.8	-	2.0	2.8	-	MHz
$\begin{array}{c c c c c c c c c c c c c c c c c c c $		-15 V, T <sub>A</sub> = 25°0	C, unless	otherwi	se noted.	)			
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Input Offset Voltage ( $R_S \le 10 \text{ k}\Omega$ )	VIO	-	1.0	5.0	-	2.0	6.0	mV
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Input Offset Current	lio	-	20	200	-	20	200	nA
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Input Bias Current (Note 1)	l <sub>IB</sub>	-	80	500	-	80	500	nA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Input Resistance	rj	0.3	2.0	-	0.3	2.0	-	MΩ
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Input Capacitance	Ci	-	1.4	-	-	1.4	-	pF
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Common Mode Input Voltage Range	VICR	±12	±13	-	±12	±13	-	V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Large Signal Voltage Gain (V_O = $\pm 10$ V, R <sub>L</sub> = 2.0 k $\Omega$ )	AVOL	50	200	-	20	200	-	V/mV
	Output Resistance	r <sub>o</sub>	-	75	-	-	75	-	Ω
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Common Mode Rejection (R_S $\leq$ 10 k $\Omega$ )	CMR	70	90	-	70	90	-	dB
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Supply Voltage Rejection Ratio (R_S $\leq$ 10 k $\Omega$ )	PSRR	-	30	150	-	30	150	μV/V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $		VO							V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $									
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		lsc			40			40	mA
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	•		_	2.3	5.0	_	2.3	5.6	mA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Power Consumption (Both Amplifiers)		_	70	150	_	70	170	mW
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			_	0.3	_	_	0.3	_	us
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			-	1					
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$				_					V/µs
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			igh to T <sub>lo</sub>			ise note	d. See N		
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		VIO	-	1.0	6.0	-	-	7.5	mV
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		IIO		70	200	_	_	_	nA
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	$(T_A = T_{IOW})$		-				-	-	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$(T_A = 0^\circ \text{ to } +70^\circ \text{C})$		-	-	-	-	-	300	
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		IВ		20	500				nA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $			_	1		_	_	_	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $			-	-	-	-	-	800	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Common Mode Input Voltage Range	VICR	±12	±13	-	-	-	-	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Large Signal Voltage Gain (V_O = $\pm 10$ V, R <sub>L</sub> = 2.0 k $\Omega$ )	AVOL	25	-	-	15	-	-	V/mV
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Common Mode Rejection (R <sub>S</sub> $\leq$ 10 k $\Omega$ )	CMR	70	90	-	-	-	-	dB
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Supply Voltage Rejection Ratio (R_S $\leq$ 10 k\Omega)	PSRR	-	30	150	-	-	-	μV/V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		VO							V
Supply Currents (Both Amplifiers)ID $  -$									
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		٦							mA
Power Consumption (Both Amplifiers) (T <sub>A</sub> = T <sub>high</sub> ) P <sub>C</sub> 135 150 mW	$(T_A = T_{high})$								
$(T_A = T_{high})$ 135 150			-	-	6.0	-	-	6.7	
	,		_	_	135	_	_	150	mvv
			-	-	180	-	-		

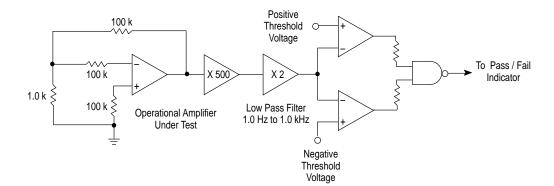
## **FREQUENCY CHARACTERISTICS** ( $V_{CC} = +15 V$ , $V_{FF} = -15 V$ , $T_A = 25^{\circ}C$ )

**NOTES:** 1. I<sub>IB</sub> is out of the amplifier due to PNP input transistors. 2. T<sub>high</sub> = +70°C, T<sub>Iow</sub> = 0°C.





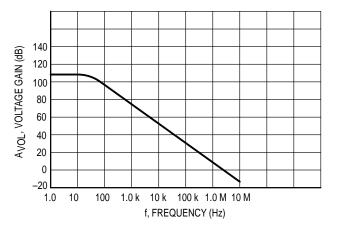
#### Figure 5. Burst Noise Test Circuit

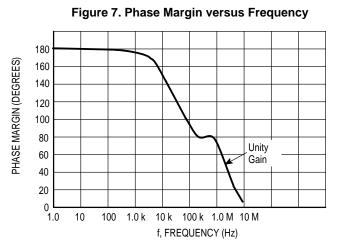


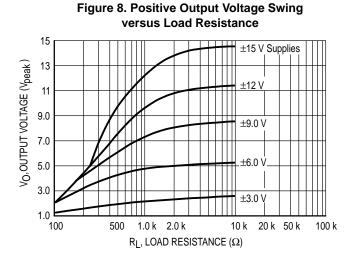
Unlike conventional peak reading or RMS meters, this system was especially designed to provide the quick response time essential to burst (popcorn) noise testing.

The test time employed is 10 sec and the 20  $\mu$ V peak limit refers to the operational amplifier input thus eliminating errors in the closed loop gain factor of the operational amplifier.

#### Figure 6. Open Loop Frequency Response







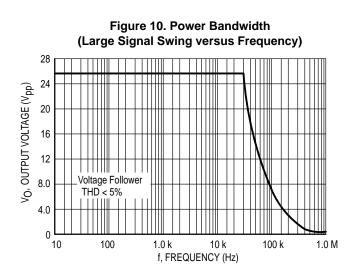


Figure 9. Negative Output Voltage Swing versus Load Resistance

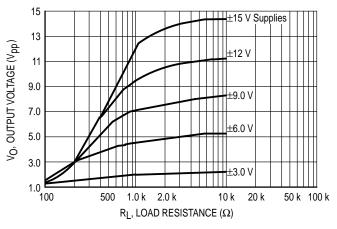
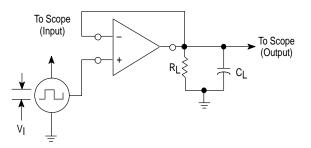
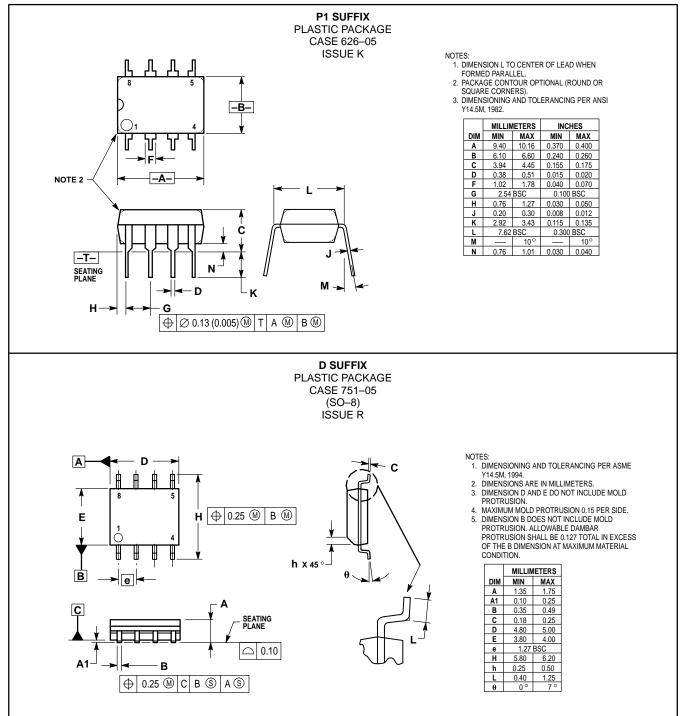


Figure 11. Transient Response Test Circuit



### **OUTLINE DIMENSIONS**



## MC4558AC MC4558C NOTES

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